

AMIC

LP62S2048A-T Series

Preliminary

256K X 8 BIT LOW VOLTAGE CMOS SRAM

Document Title

256K X 8 BIT LOW VOLTAGE CMOS SRAM

Revision History

<u>Rev. No.</u>	<u>History</u>
0.0	Initial issue

<u>Issue Date</u>	<u>Remark</u>
June 24, 2002	Preliminary



LP62S2048A-T Series

Preliminary

256K X 8 BIT LOW VOLTAGE CMOS SRAM

Features

- Power supply range: 2.7V to 3.3V
- Access times: 55/70 ns (max.)
- Current:
 - Very low power version: Operating: 55ns: 25mA (max.)
70ns: 20mA (max.)
 - Standby: 10 μ A (max.)
- Full static operation, no clock or refreshing required
- All inputs and outputs are directly TTL-compatible
- Common I/O using three-state output
- Output enable and two chip enable inputs for easy application
- Data retention voltage: 2V (min.)
- Available in 32-pin SOP, TSOP, TSSOP (8X13.4mm) and 36-pin CSP packages

General Description

The LP62S2048A-T is a low operating current 2,097,152-bit static random access memory organized as 262,144 words by 8 bits and operates on a low power supply range: 2.7V to 3.3V. It is built using AMIC's high performance CMOS process.

Inputs and three-state outputs are TTL compatible and allow for direct interfacing with common system bus structures.

Two chip enable inputs are provided for POWER-DOWN and device enable and an output enable input is included for easy interfacing.

Data retention is guaranteed at a power supply voltage as low as 2V.

Product Family

Product Family	Operating Temperature	VCC Range	Speed	Power Dissipation			Package Type
				Data Retention (I _{CCDR} , Typ.)	Standby (I _{SB1} , Typ.)	Operating (I _{CC2} , Typ.)	
LP62S2048A	-25°C ~ +85°C	2.7V~3.3V	55ns / 70ns	0.5 μ A	0.5 μ A	3mA	32L SOP 32L TSOP 32L TSSOP 36L CSP

1. Typical values are measured at VCC = 3.0V, T_A = 25°C and not 100% tested.

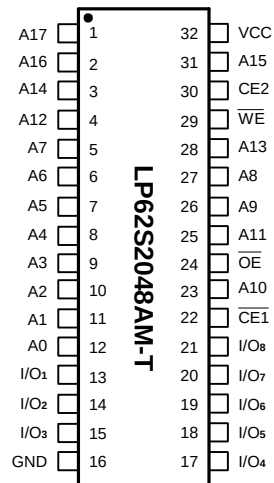
2. Data retention current VCC = 2.0V.



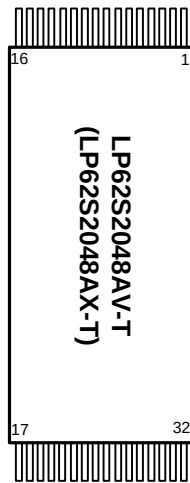
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Pin Configurations

■ SOP



■ TSOP/(TSSOP)



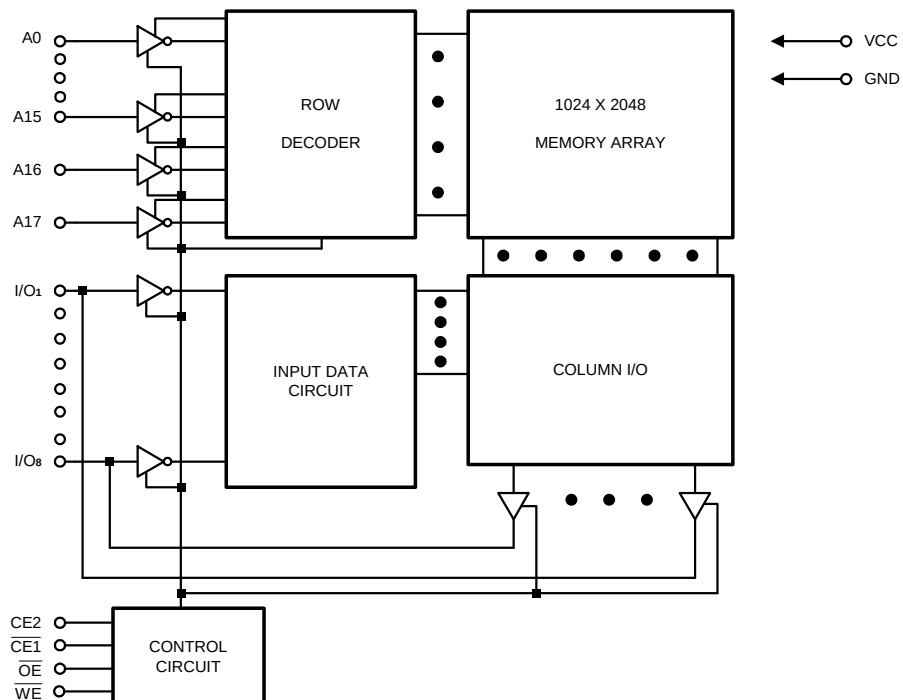
■ CSP (Chip Size Package)

36-pin Top View

	1	2	3	4	5	6
A	A0	A1	CE2	A3	A6	A8
B	I/O ₅	A2	WE	A4	A7	I/O ₁
C	I/O ₆		NC	A5		I/O ₂
D	GND					VCC
E	VCC					GND
F	I/O ₇		NC	A17		I/O ₃
G	I/O ₈	OE	CE1	A16	A15	I/O ₄
H	A9	A10	A11	A12	A13	A14

Pin No.	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
Pin Name	A11	A9	A8	A13	WE	CE2	A15	VCC	A17	A16	A14	A12	A7	A6	A5	A4
Pin No.	17	18	19	20	21	22	23	24	25	26	27	28	29	30	31	32
Pin Name	A3	A2	A1	A0	I/O ₁	I/O ₂	I/O ₃	GND	I/O ₄	I/O ₅	I/O ₆	I/O ₇	I/O ₈	CE1	A10	OE

Block Diagram





LP62S2048A-T Series

Pin Description - SOP

Pin No.	Symbol	Description
1 - 12, 23, 25 - 28, 31	A0 - A17	Address Inputs
13 - 15, 17 - 21	I/O ₁ - I/O ₈	Data Input/Outputs
16	GND	Ground
22	$\overline{\text{CE1}}$	Chip Enable
24	$\overline{\text{OE}}$	Output Enable
29	$\overline{\text{WE}}$	Write Enable
30	CE2	Chip Enable
32	VCC	Power Supply

Pin Descriptions - TSOP/TSSOP

Pin No.	Symbol	Description
1 - 4, 7, 9 - 20, 31	A0 - A17	Address Inputs
5	$\overline{\text{WE}}$	Write Enable
6	CE2	Chip Enable
8	VCC	Power Supply
9	NC	No Connection
21 - 23, 25 - 29	I/O ₁ - I/O ₈	Data Input/Outputs
24	GND	Ground
30	$\overline{\text{CE1}}$	Chip Enable
32	$\overline{\text{OE}}$	Output Enable

Pin Description - CSP

Symbol	Description	Symbol	Description
A0 - A17	Address Inputs	NC	No Connection
$\overline{\text{WE}}$	Write Enable	I/O ₁ - I/O ₈	Data Input/Output
$\overline{\text{OE}}$	Output Enable	VCC	Power Supply
$\overline{\text{CE1}}$	Chip Enable	GND	Ground
CE2	Chip Enable	--	--

Recommended DC Operating Conditions

(T_A = -25°C to + 85°C)

Symbol	Parameter	Min.	Typ.	Max.	Unit
VCC	Supply Voltage	2.7	3.0	3.3	V
GND	Ground	0	0	0	V
V _{IH}	Input High Voltage	2.0	-	VCC + 0.3	V
V _{IL}	Input Low Voltage	-0.3	-	+0.6	V
C _L	Output Load	-	-	30	pF
TTL	Output Load	-	-	1	-



LP62S2048A-T Series

Absolute Maximum Ratings*

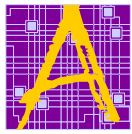
VCC to GND -0.5V to + 4.6V
 IN, IN/OUT Volt to GND -0.5V to VCC + 0.5V
 Operating Temperature, Topr -25°C to + 85°C
 Storage Temperature, Tstg -55°C to + 125°C
 Temperature Under Bias, Tbias -10°C to + 85°C
 Power Dissipation, Pr 0.7W
 Soldering Temp. & Time 260°C, 10 sec

*Comments

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

DC Electrical Characteristics (TA = -25°C to + 85°C, VCC = 2.7V to 3.3V, GND = 0V)

Symbol	Parameter	LP62S2048A-55LLT		LP62S2048A-70LLT		Unit	Conditions
		Min.	Max.	Min.	Max.		
I _{LI}	Input Leakage Current	-	1	-	1	μA	V _{IN} = GND to VCC
I _{LO}	Output Leakage Current	-	1	-	1	μA	$\overline{CE1} = V_{IH}$ or $CE2 = V_{IL}$ or $\overline{OE} = V_{IH}$ or $\overline{WE} = V_{IL}$ V _{I/O} = GND to VCC
I _{CC}	Active Power Supply Current	-	3	-	3	mA	$\overline{CE1} = V_{IL}$, CE2 = V _{IH} I _{I/O} = 0mA
I _{CC1}	Dynamic Operating Current	-	25	-	20	mA	Min. Cycle, Duty = 100% $\overline{CE1} = V_{IL}$, CE2 = V _{IH} I _{I/O} = 0mA
I _{CC2}		-	5	-	5	mA	$\overline{CE1} = V_{IL}$, CE2 = V _{IH} V _{IH} = VCC, V _{IL} = 0V f = 1 MHz, I _{I/O} = 0mA
I _{SB}	Standby Power Supply Current	-	0.5	-	0.5	mA	$\overline{CE1} = V_{IH}$ or CE2 = V _{IL}
I _{SB1}		-	10	-	10	μA	$\overline{CE1} \geq VCC - 0.2V$ V _{IN} ≥ 0V
I _{SB2}		-	10	-	10	μA	CE2 ≤ 0.2V V _{IN} ≥ 0V
V _{OL}	Output Low Voltage	-	0.4	-	0.4	V	I _{OL} = 2.1mA
V _{OH}	Output High Voltage	2.2	-	2.2	-	V	I _{OH} = -1.0mA

**Truth Table**

Mode	$\overline{\text{CE1}}$	CE2	$\overline{\text{OE}}$	$\overline{\text{WE}}$	I/O Operation	Supply Current
Standby	H	X	X	X	High Z	I _{SB} , I _{SB1}
	X	L	X	X	High Z	I _{SB} , I _{SB2}
Output Disable	L	H	H	H	High Z	I _{CC} , I _{CC1} , I _{CC2}
Read	L	H	L	H	D _{OUT}	I _{CC} , I _{CC1} , I _{CC2}
Write	L	H	X	L	D _{IN}	I _{CC} , I _{CC1} , I _{CC2}

Note: X = H or L

Capacitance (T_A = 25°C, f = 1.0MHz)

Symbol	Parameter	Min.	Max.	Unit	Conditions
C _{IN} *	Input Capacitance		6	pF	V _{IN} = 0V
C _{I/O} *	Input/Output Capacitance		8	pF	V _{I/O} = 0V

* These parameters are sampled and not 100% tested.



LP62S2048A-T Series

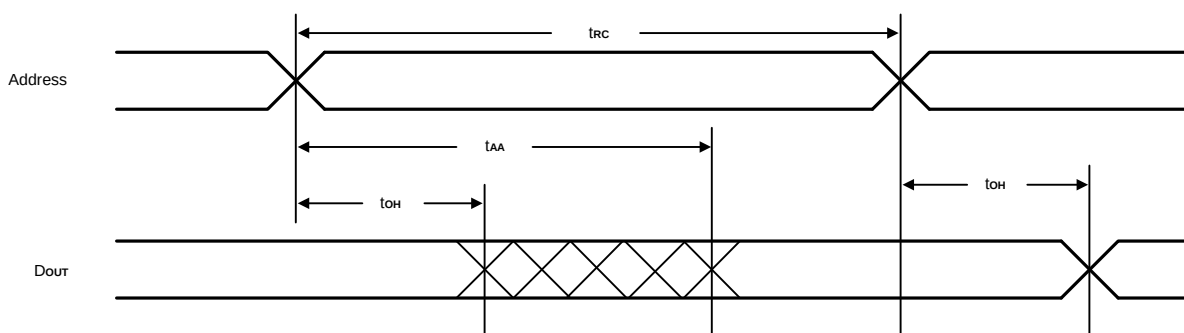
AC Characteristics (T_A = -25°C to +85°C, V_{CC} = 2.7V to 3.3V)

Symbol	Parameter		LP62S2048A-55LLT		LP62S2048A-70LLT		Unit
			Min.	Max.	Min.	Max.	
Read Cycle							
t _{RC}	Read Cycle Time		55	-	70	-	ns
t _{AA}	Address Access Time		-	55	-	70	ns
t _{ACE1}	Chip Enable Access Time	$\overline{\text{CE1}}$	-	55	-	70	ns
t _{ACE2}		CE2	-	55	-	70	ns
t _{OE}	Output Enable to Output Valid		-	25	-	35	ns
t _{CLZ1}	Chip Enable to Output in Low Z	$\overline{\text{CE1}}$	10	-	10	-	ns
t _{CLZ2}		CE2	10	-	10	-	ns
t _{OLZ}	Output Enable to Output in Low Z		5	-	5	-	ns
t _{CHZ1}	Chip Disable to Output in High Z	$\overline{\text{CE1}}$	0	20	0	25	ns
t _{CHZ2}		CE2	0	20	0	25	ns
t _{OHZ}	Output Disable to Output in High Z		0	20	0	25	ns
t _{OH}	Output Hold from Address Change		5	-	10	-	ns
Write Cycle							
t _{WC}	Write Cycle Time		55	-	70	-	ns
t _{CW}	Chip Enable to End of Write		50	-	60	-	ns
t _{AS}	Address Setup Time		0	-	0	-	ns
t _{AW}	Address Valid to End of Write		50	-	60	-	ns
t _{WP}	Write Pulse Width		40	-	50	-	ns
t _{WR}	Write Recovery Time		0	-	0	-	ns
t _{WHZ}	Write to Output in High Z		0	25	0	25	ns
t _{DW}	Data to Write Time Overlap		25	-	30	-	ns
t _{DH}	Data Hold from Write Time		0	-	0	-	ns
t _{OW}	Output Active from End of Write		5	-	5	-	ns

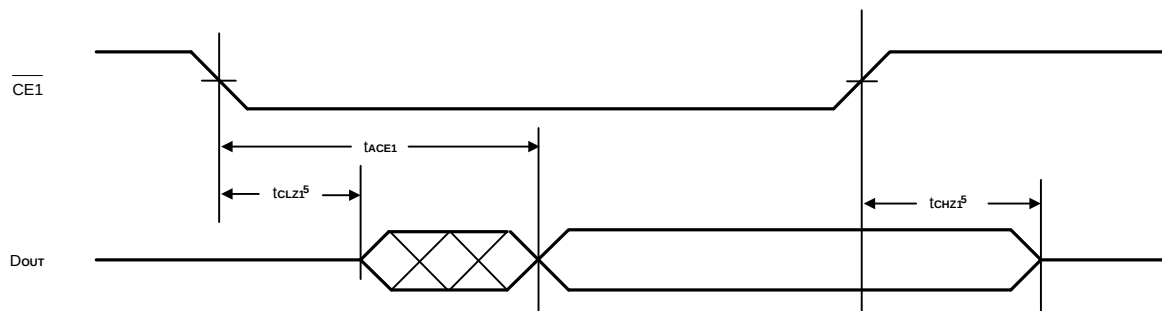
Notes: t_{CHZ1}, t_{CHZ2}, t_{OHZ}, and t_{WHZ} are defined as the time at which the outputs achieve the open circuit condition and are not referred to output voltage levels.

Timing Waveforms

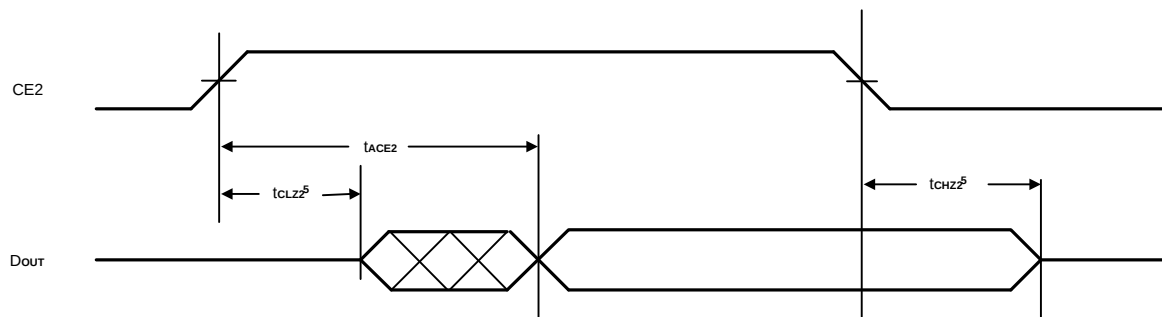
Read Cycle 1 (1, 2, 4)

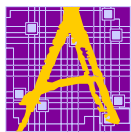


Read Cycle 2 (1, 3, 4, 6)



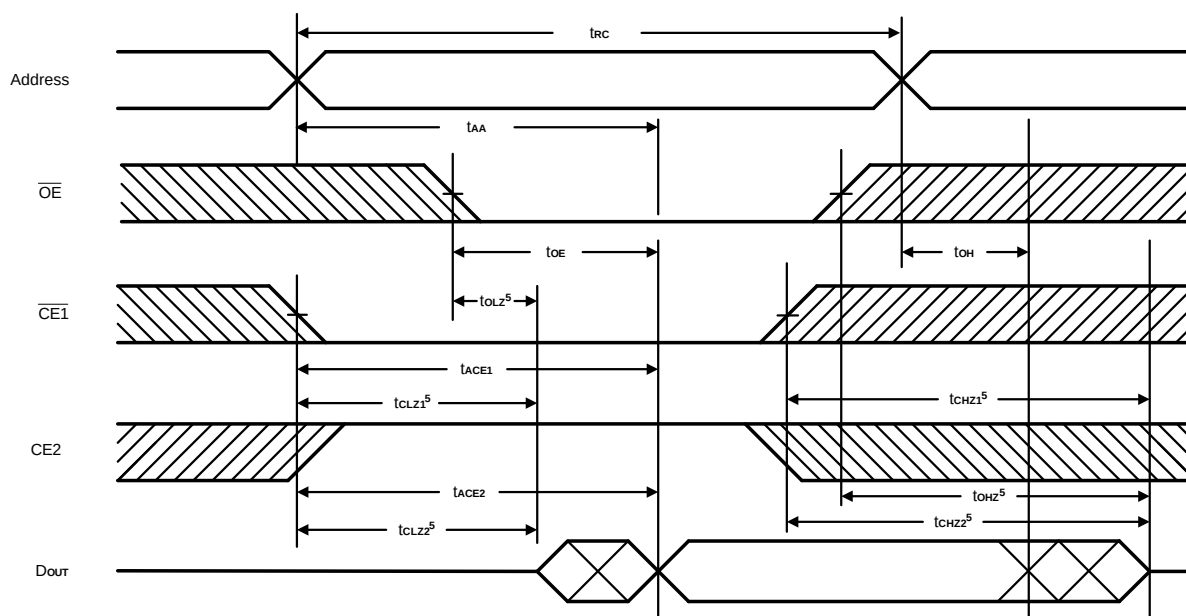
Read Cycle 3 (1, 4, 7, 8)



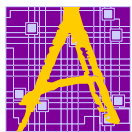


Timing Waveforms (continued)

Read Cycle 4 ⁽¹⁾



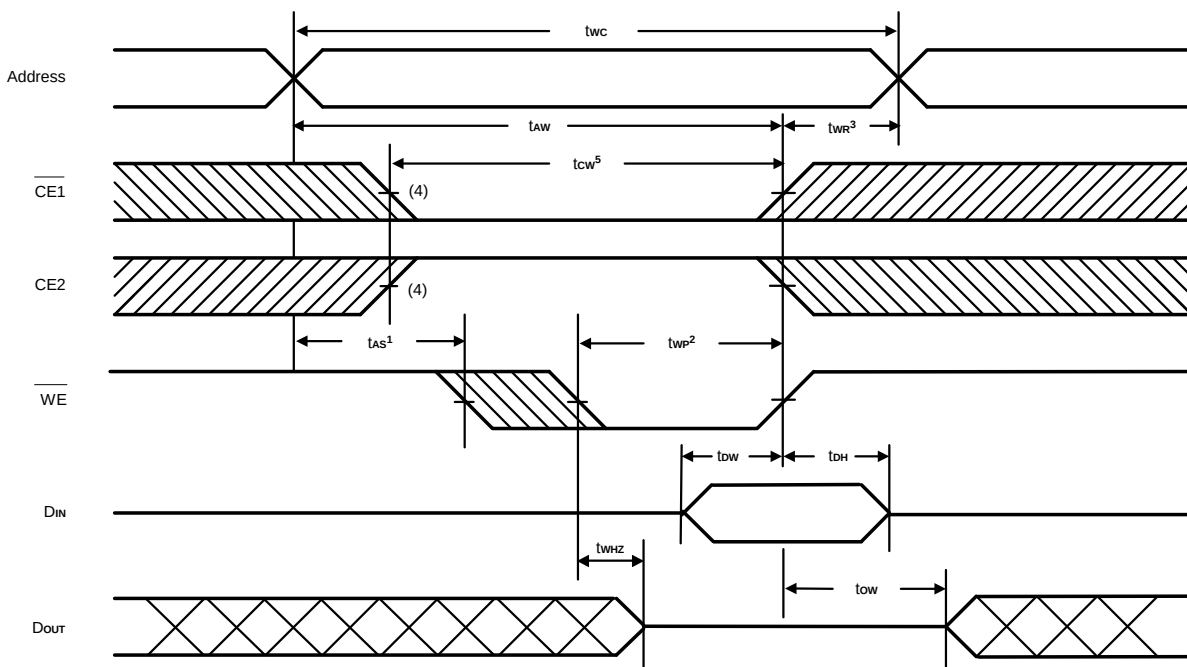
- Notes:
1. $\overline{WE}$ is high for Read Cycle.
 2. Device is continuously enabled $\overline{CE1} = V_{IL}$ and $CE2 = V_{IH}$.
 3. Address valid prior to or coincident with $\overline{CE1}$ transition low.
 4. $\overline{OE} = V_{IL}$.
 5. Transition is measured $\pm 500\text{mV}$ from steady state. This parameter is sampled and not 100% tested.
 6. $\overline{CE2}$ is high.
 7. $\overline{CE1}$ is low.
 8. Address valid prior to or coincident with $CE2$ transition high.

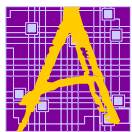


Timing Waveforms (continued)

Write Cycle 1 ⁽⁶⁾

(Write Enable Controlled)

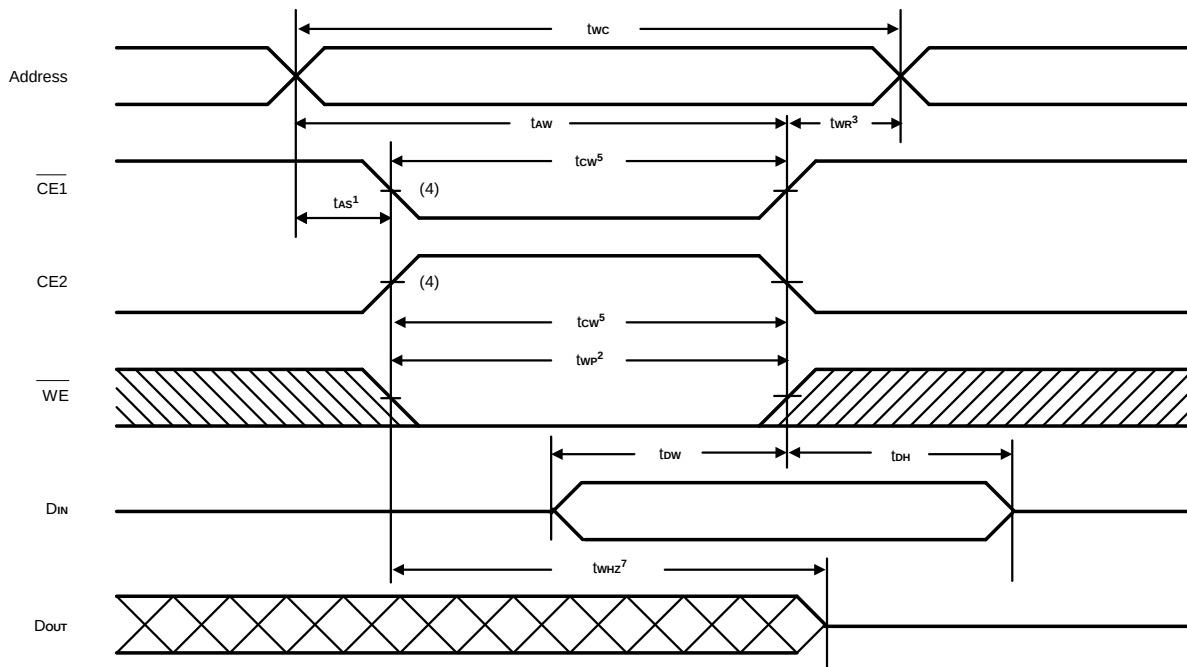




Timing Waveforms (continued)

Write Cycle 2

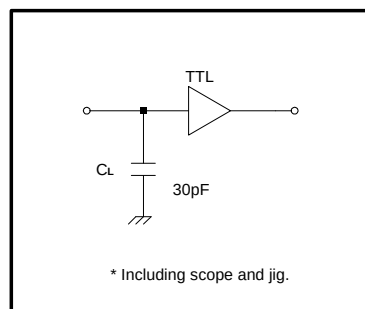
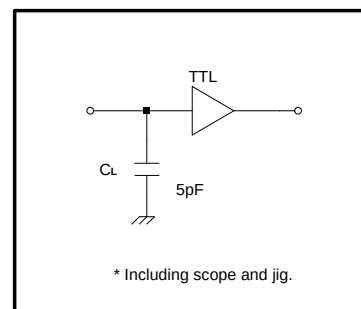
(Chip Enable Controlled)



- Notes:
1. t_{as} is measured from the address valid to the beginning of Write.
 2. A Write occurs during the overlap (t_{wp}) of a low $\overline{CE1}$, a high $\overline{CE2}$ and a low $\overline{WE}$.
 3. t_{wr} is measured from the earliest of $\overline{CE1}$ or $\overline{WE}$ going high or $\overline{CE2}$ going low to the end of the Write cycle.
 4. If the $\overline{CE1}$ low transition or the $\overline{CE2}$ high transition occurs simultaneously with the $\overline{WE}$ low transition or after the $\overline{WE}$ transition, outputs remain in a high impedance state.
 5. t_{cw} is measured from the later of $\overline{CE1}$ going low or $\overline{CE2}$ going high to the end of Write.
 6. $\overline{OE}$ is continuously low. ($\overline{OE} = V_{IL}$)
 7. Transition is measured $\pm 500\text{mV}$ from steady state. This parameter is sampled and not 100% tested.

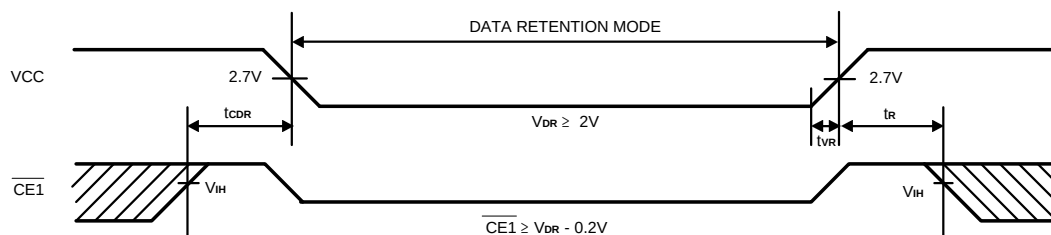
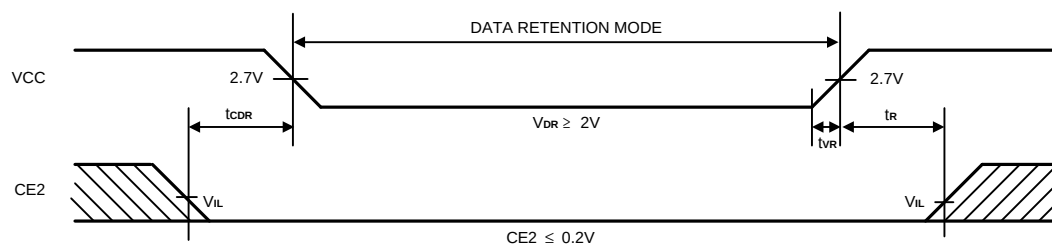
AC Test Conditions

Input Pulse Levels	0.4V to 2.4V
Input Rise and Fall Time	5 ns
Input and Output Timing Reference Levels	1.5V
Output Load	See Figures 1 and 2


Figure 1. Output Load

Figure 2. Output Load for t_{CLZ1} , t_{CLZ2} , t_{OHZ} , t_{OLZ} , t_{CHZ1} , t_{CHZ2} , t_{WHZ} , and t_{OW}
Data Retention Characteristics ($T_A = -25^{\circ}\text{C}$ to 85°C)

Symbol	Parameter	Min.	Max.	Unit	Conditions
V_{DR1}	VCC for Data Retention	2.0	3.3	V	$\overline{CE1} \geq V_{CC} - 0.2V$
V_{DR2}		2.0	3.3	V	$CE2 \leq 0.2V$,
I_{CCDR1}	Data Retention Current	-	5**	μA	$V_{CC} = 2.0V$, $\overline{CE1} \geq V_{CC} - 0.2V$, $V_{IN} \geq 0V$
I_{CCDR2}		-	5**	μA	$V_{CC} = 2.0V$, $CE2 \leq 0.2V$, $V_{IN} \geq 0V$
t_{CDR}	Chip Disable to Data Retention Time	0	-	ns	See Retention Waveform
t_R	Operation Recovery Time	t_{RC}	-	ns	
t_{VR}	VCC Rising Time from Data Retention Voltage to Operating Voltage	5	-	ms	

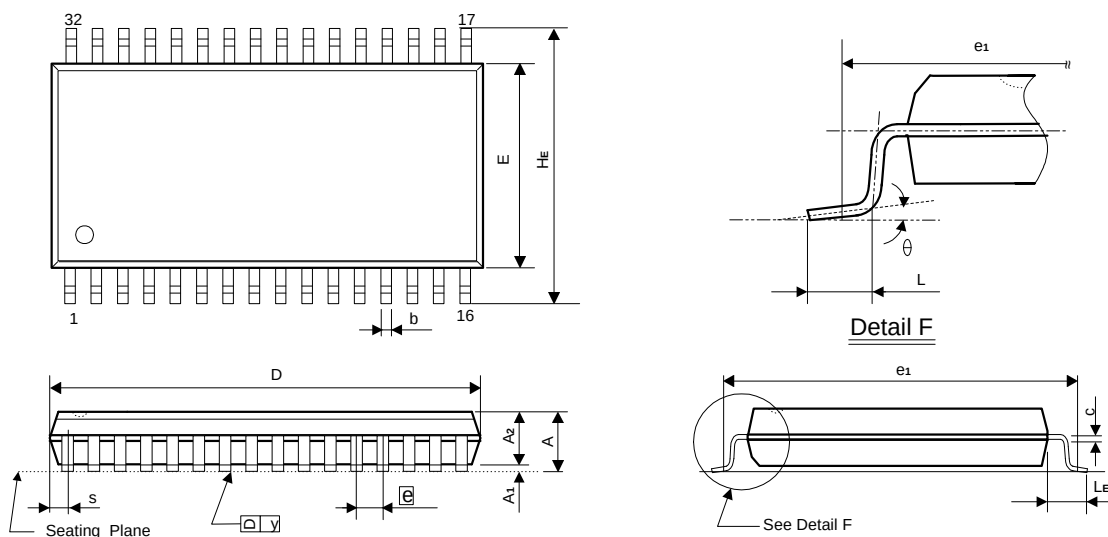
** LP62S2048A-55LLT/70LLT I_{CCDR} : max. 1 μA at $T_A = 0^{\circ}\text{C}$ to $+40^{\circ}\text{C}$

Low VCC Data Retention Waveform (1) (CE1 Controlled)

Low VCC Data Retention Waveform (2) (CE2 Controlled)

Ordering Information

Part No.	Access Time (ns)	Operating Current Max. (mA)	Standby Current Max. (mA)	Package
LP62S2048AM-55LLT	55	25	10	32L SOP
LP62S2048AV-55LLT		25	10	32L TSOP
LP62S2048AX-55LLT		25	10	32L TSSOP
LP62S2048AU-55LLT		25	10	36L CSP
LP62S2048AM-70LLT	70	20	10	32L SOP
LP62S2048AV-70LLT		20	10	32L TSOP
LP62S2048AX-70LLT		20	10	32L TSSOP
LP62S2048AU-70LLT		20	10	36L CSP

Package Information
SOP (W.B.) 32L Outline Dimensions

unit: inches/mm



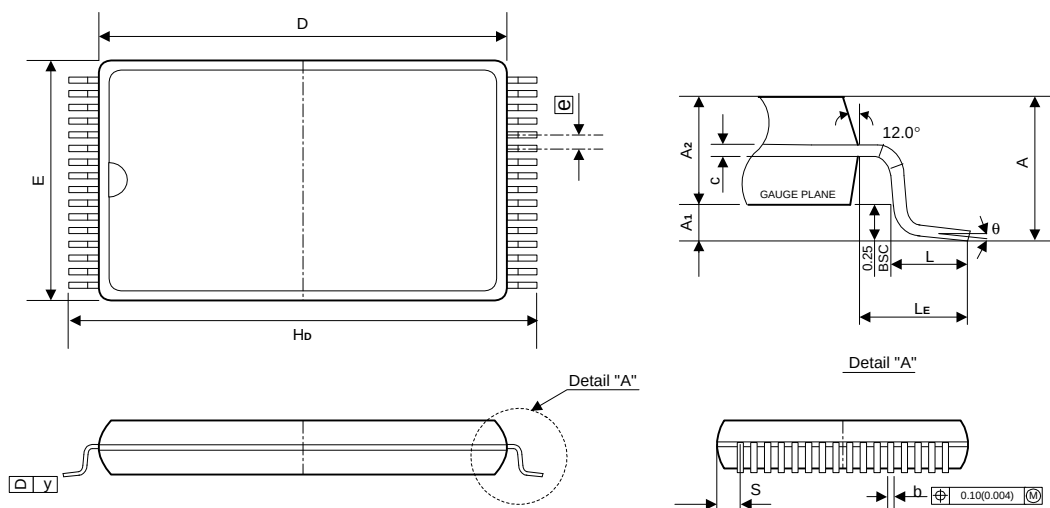
Symbol	Dimensions in inches	Dimensions in mm
A	0.118 Max.	3.00 Max.
A ₁	0.004 Min.	0.10 Min.
A ₂	0.106±0.005	2.69±0.13
b	0.016 +0.004 -0.002	0.41 +0.10 -0.05
c	0.008 +0.004 -0.002	0.20 +0.10 -0.05
D	0.805 Typ. (0.820 Max.)	20.45 Typ. (20.83 Max.)
E	0.445±0.010	11.30±0.25
$\bar{e}$	0.050 ±0.006	1.27±0.15
e ₁	0.525 NOM.	13.34 NOM.
HE	0.556±0.010	14.12±0.25
L	0.031±0.008	0.79±0.20
LE	0.055±0.008	1.40±0.20
S	0.044 Max.	1.12 Max.
y	0.004 Max.	0.10 Max.
θ	0° ~ 10°	0° ~ 10°

Notes:

1. The maximum value of dimension D includes end flash.
2. Dimension E does not include resin fins.
3. Dimension e₁ is for PC Board surface mount pad pitch design reference only.
4. Dimension S includes end flash.

Package Information
TSOP 32L TYPE I (8 X 20mm) Outline Dimensions

unit: inches/mm



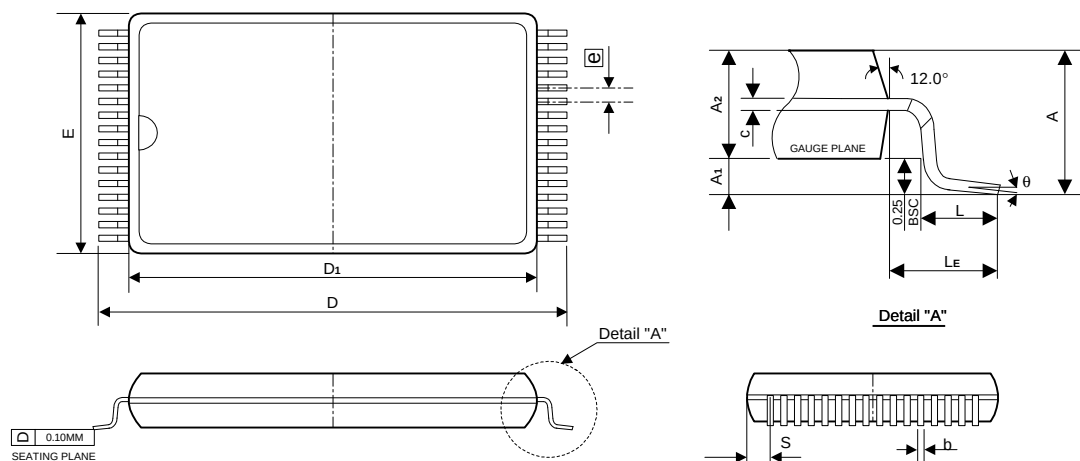
Symbol	Dimensions in inches	Dimensions in mm
A	0.047 Max.	1.20 Max.
A ₁	0.004±0.002	0.10±0.05
A ₂	0.039±0.002	1.00±0.05
b	0.008±0.001	0.20±0.03
c	0.006±0.001	0.15±0.02
D	0.724±0.004	18.40±0.10
E	0.315±0.004	8.00±0.10
e	0.020 TYP.	0.50 TYP.
H _D	0.787±0.007	20.00±0.20
L	0.020±0.004	0.50±0.10
L _E	0.031 TYP.	0.80 TYP.
S	0.0167 TYP.	0.425 TYP.
Y	0.004 Max.	0.10 Max.
θ	0° ~ 6°	0° ~ 6°

Notes:

1. The maximum value of dimension D includes end flash.
2. Dimension E does not include resin fins.
3. Dimension e₁ is for PC Board surface mount pad pitch design reference only.
4. Dimension S includes end flash.

Package Information
TSSOP 32L TYPE I (8 X 13.4mm) Outline Dimensions

unit: inches/mm



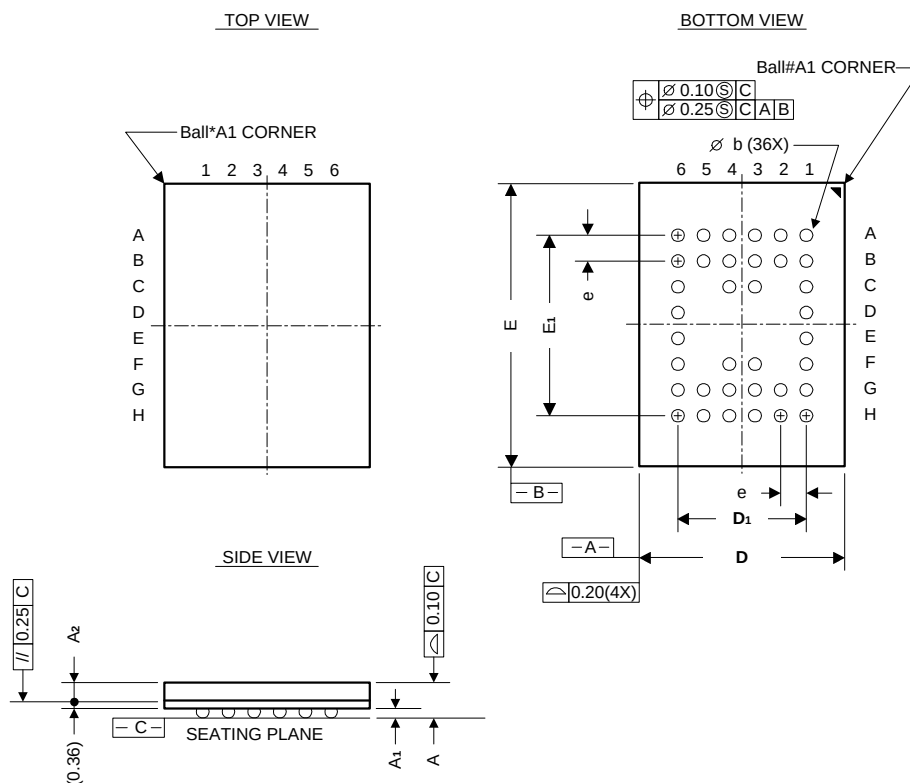
Symbol	Dimensions in inches	Dimensions in mm
A	0.049 Max.	1.25 Max.
A ₁	0.002 Min.	0.05 Min.
A ₂	0.039±0.002	1.00±0.05
b	0.008±0.001	0.20±0.03
c	0.006±0.0003	0.15±0.008
E	0.315±0.004	8.00±0.10
e	0.020 TYP.	0.50 TYP.
D	0.528±0.008	13.40±0.20
D ₁	0.465±0.004	11.80±0.10
L	0.02±0.008	0.50±0.20
LE	0.0266 Min.	0.675 Min.
S	0.0109 TYP.	0.278 TYP.
y	0.004 Max.	0.10 Max.
θ	0° ~ 6°	0° ~ 6°

Notes:

1. The maximum value of dimension D includes end flash.
2. Dimension E does not include resin fins.
3. Dimension e₁ is for PC Board surface mount pad pitch design reference only.
4. Dimension S includes end flash.

Package Information
36LD CSP (6 x 8 mm) Outline Dimensions

unit: mm



Symbol	Dimensions in mm		
	MIN.	NOM.	MAX.
A	1.00	1.10	1.20
A ₁	0.16	0.21	0.26
A ₂	0.48	0.53	0.58
D	5.80	6.00	6.20
E	7.80	8.00	8.20
D ₁	---	3.75	---
E ₁	---	5.25	---
e	---	0.75	---
b	0.25	0.30	0.35

Note:

1. THE BALL DIAMETER, BALL PITCH, STAND-OFF & PACKAGE THICKNESS ARE DIFFERENT FROM JEDEC SPEC MO192 (LOW PROFILE BGA FAMILY).
2. PRIMARY DATUM C AND SEATING PLANE ARE DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
3. DIMENSION b IS MEASURED AT THE MAXIMUM.
4. THERE SHALL BE A MINIMUM CLEARANCE OF 0.25mm BETWEEN THE EDGE OF THE SOLDER BALL AND THE BODY EDGE.